

- Under thermal equilibrium, which of the following approach(es) can create a built-in electric field in a semiconductor?(A)p-n junction(B) spatial variation of doping concentration(C)heterojunction(D)Schottky contacts.(3%)
- (a)As shown in Fig.1, the five forward I-V curves correspond to five p-n junction diodes made from different semiconductors with corresponding energy band gap $E_{g1}, E_{g2}, E_{g3}, E_{g4}$ and E_{g5} . Please identify which of the following item(s) is(are) true.(A) $E_{g3} > E_{g4}$ (B) $E_{g5} > E_{g4}$ (C) $E_{g3} < E_{g4}$ (D) $E_{g3} > E_{g2} > E_{g1}$ (E) $E_{g1} > E_{g2} > E_{g3}$ (3%)

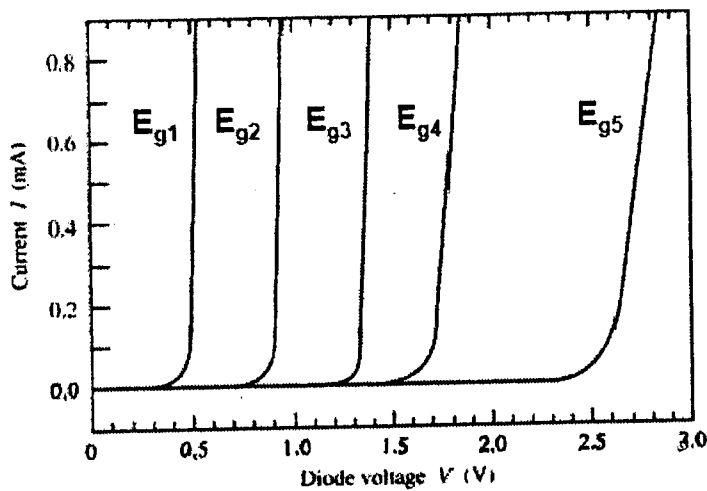


Fig.1

- (b) As shown in Fig.2, if the five forward I-V curves correspond to a GaAs junction diode operated at different temperatures, please identify which of the following item(s) is(are) true.(A) $T_1 > T_2$ (B) $T_3 > T_4$ (C) $T_2 > T_5$ (D) $T_3 > T_2$ (E) $T_5 > T_4$ (3%)

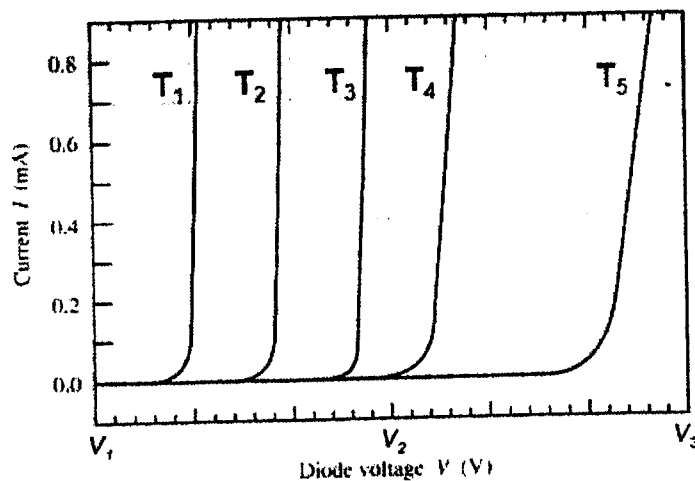


Fig.2

(背面仍有題目,請繼續作答)

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(c) As shown in Fig.3, if the five light output power-current (L-I) curves correspond to a GaAs LED operated at different pulsed injection currents, i.e., different duty cycles, which is defined in the inset of Fig.3. Please identify which of the following items is(are) true. (A) duty1 > duty 2 (B) duty 3 > duty 4 (C) duty 2 > duty 5 (D) duty 3 > duty 2 (E) duty 5 > duty 4 (3%)

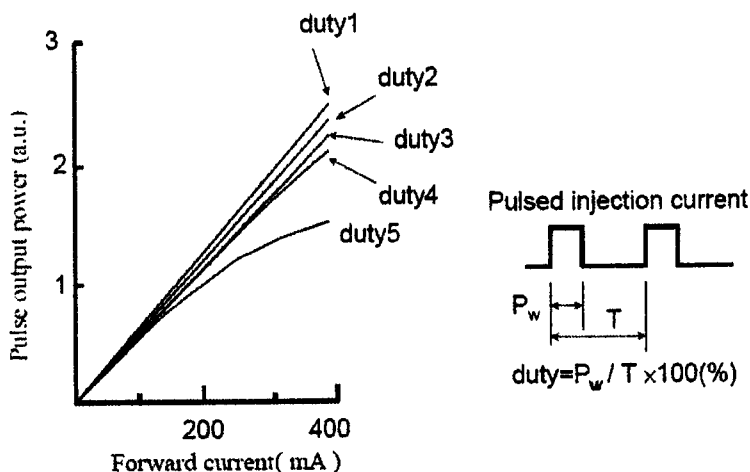


Fig.3

3. For a pn junction with $N_A=10^{17}/\text{cm}^3$ and $N_D=10^{16}/\text{cm}^3$, please find, at $T=300\text{K}$, the built-in voltage (V_0), the width depletion region (W), and the distance it extends in the p side (X_p) and in the n side (X_n) of the junction. Use $n_i=10^{16}/\text{cm}^3$ and

$\epsilon_s = 1.04 \times 10^{-12} \text{ F/cm}$. (a) $V_0 = ___ \text{ V}$ (b) $W = ___ \mu\text{m}$ (c) $X_p = ___ \mu\text{m}$ (d) $X_n = ___ \mu\text{m}$ (8%)

4. In the circuit of Fig.4, transistor Q1 and Q2 have threshold voltage $V_t=1 \text{ V}$, and the process transconductance parameter $k'_n = 100 \mu\text{A}/\text{V}^2$. Assuming $\lambda = \frac{1}{V_A} = 0$ and

$(W/L)_1=(W/L)_2=20$, please find (a) $V_1 = ___ \text{ V}$ (b) $V_2 = ___ \text{ V}$ (c) $V_3 = ___ \text{ V}$ (12%)

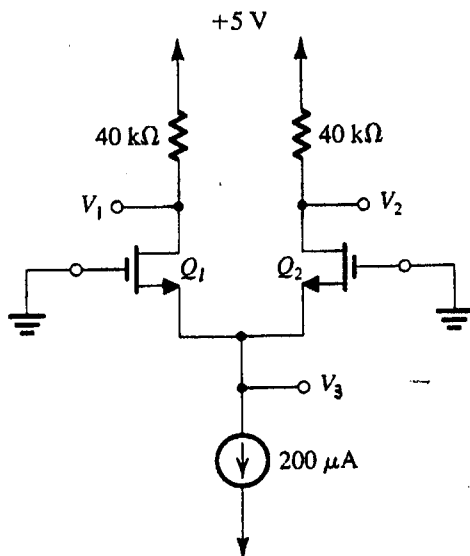


Fig.4

5. The OP amplifier in the circuit of Fig.5 is ideal with output saturation levels of $\pm 12V$. The diodes exhibit a constant $0.7V$ drop when conducting. Please find $v_- = \underline{\hspace{1cm}}V$, $v_A = \underline{\hspace{1cm}}V$ and $v_o = \underline{\hspace{1cm}}V$ for $v_I = -1V$. (12%)

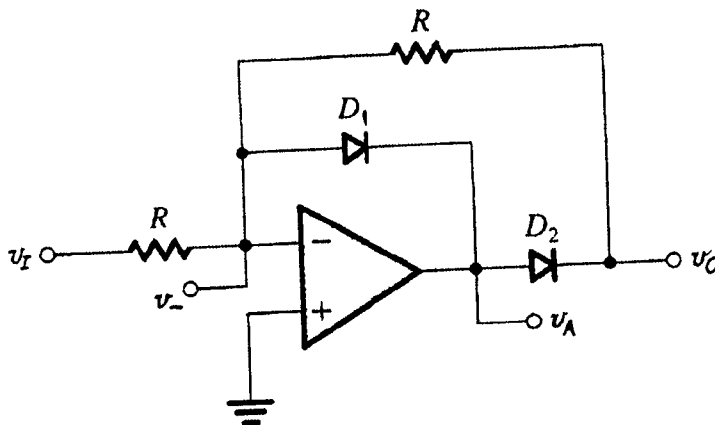


Fig.5

6. At room temperature, it is required to find the incremental (i.e., small-signal) resistance of each of the diode-connected transistors shown in the Fig.6. assume that the dc bias current $I=0.1mA$. For the MOSFET, let $\mu_n C_{ox}=200 \mu A/V^2$ and $W/L=10$.
 (a) $r = \underline{\hspace{1cm}}\Omega$ (b) $r = \underline{\hspace{1cm}}\Omega$ (8%)

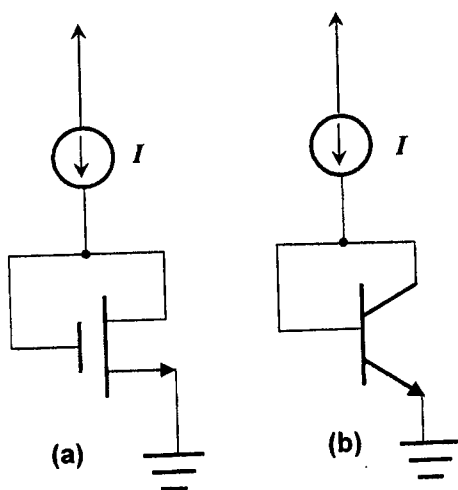


Fig.6

(背面仍有題目,請繼續作答)

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7. As shown in Fig.7, assume that the p-n and Zener diodes are ideal, and $V_z = 5V$, Find $V_2 = \underline{\hspace{2cm}}$ V and $V_3 = \underline{\hspace{2cm}}$ V when the voltage of V_1 is 16 V. (8%)

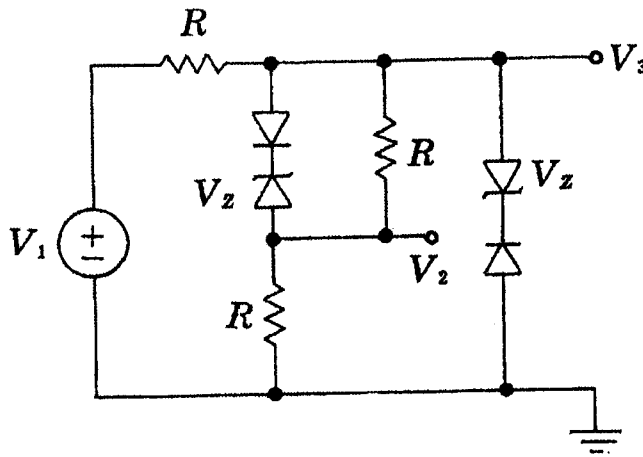


Fig.7

8. For the common-emitter amplifier shown in Fig.8, let $V_{CC} = 9V$, $R_1 = 27\text{ k}\Omega$, $R_2 = 15\text{ k}\Omega$, $R_E = 1.2\text{ k}\Omega$ and $R_C = 2.2\text{ k}\Omega$. The transistor has $\beta = 100$ and $V_A = 100V$. (a) Calculate the dc bias current I_E (b) if the amplifier operates between a source for which $R_{sig} = 10\text{ k}\Omega$ and a load of $2\text{ k}\Omega$, find the values of R_{in} , the voltage gain $A_v = v_o / v_{sig}$ and the current gain $A_i = i_o / i_i$. (20%)

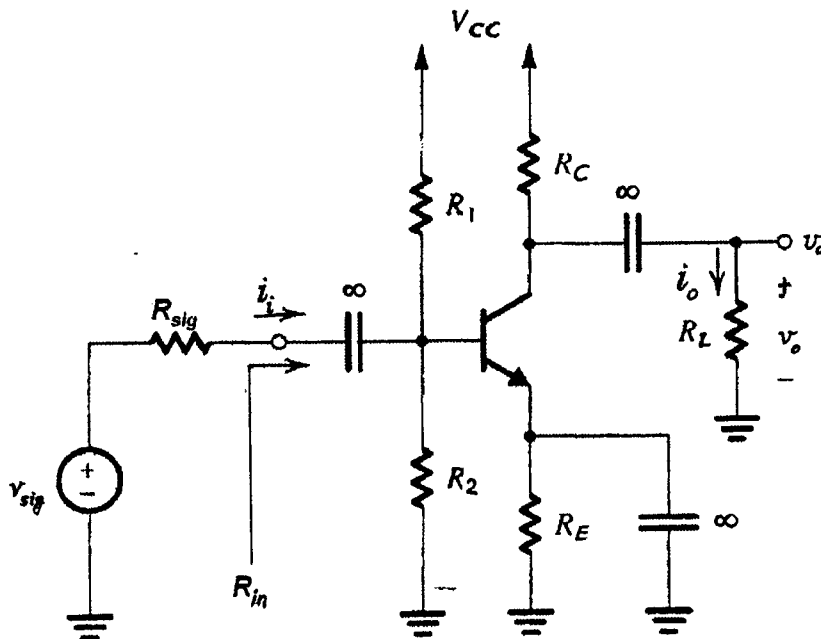


Fig.8

9. The circuit in Fig. 9 utilizes an ideal OP amplifier.
- Find I_1 , I_2 , I_3 and V_x .
 - If V_o is not to be lower than -13 V, find the maximum allowed value for R_L .
 - If R_L is varied in the range 100Ω to $1k\Omega$, what is the corresponding change in I_L and V_o ? (20%)

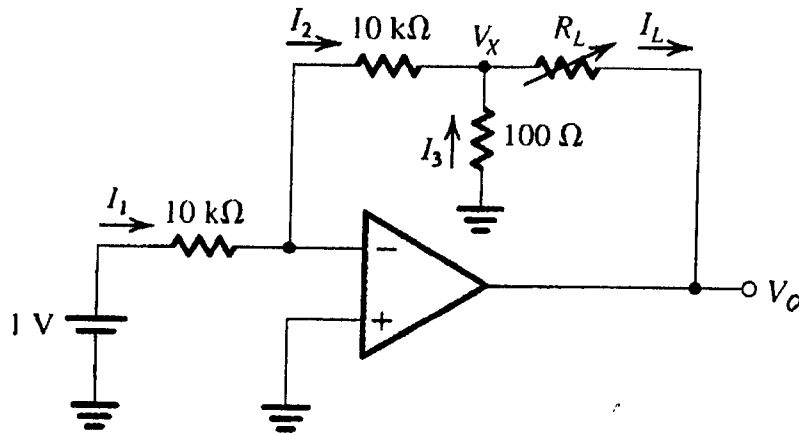


Fig. 9